Infineon Technologies - MB96F696RBPMC-GSE1 Datasheet

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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

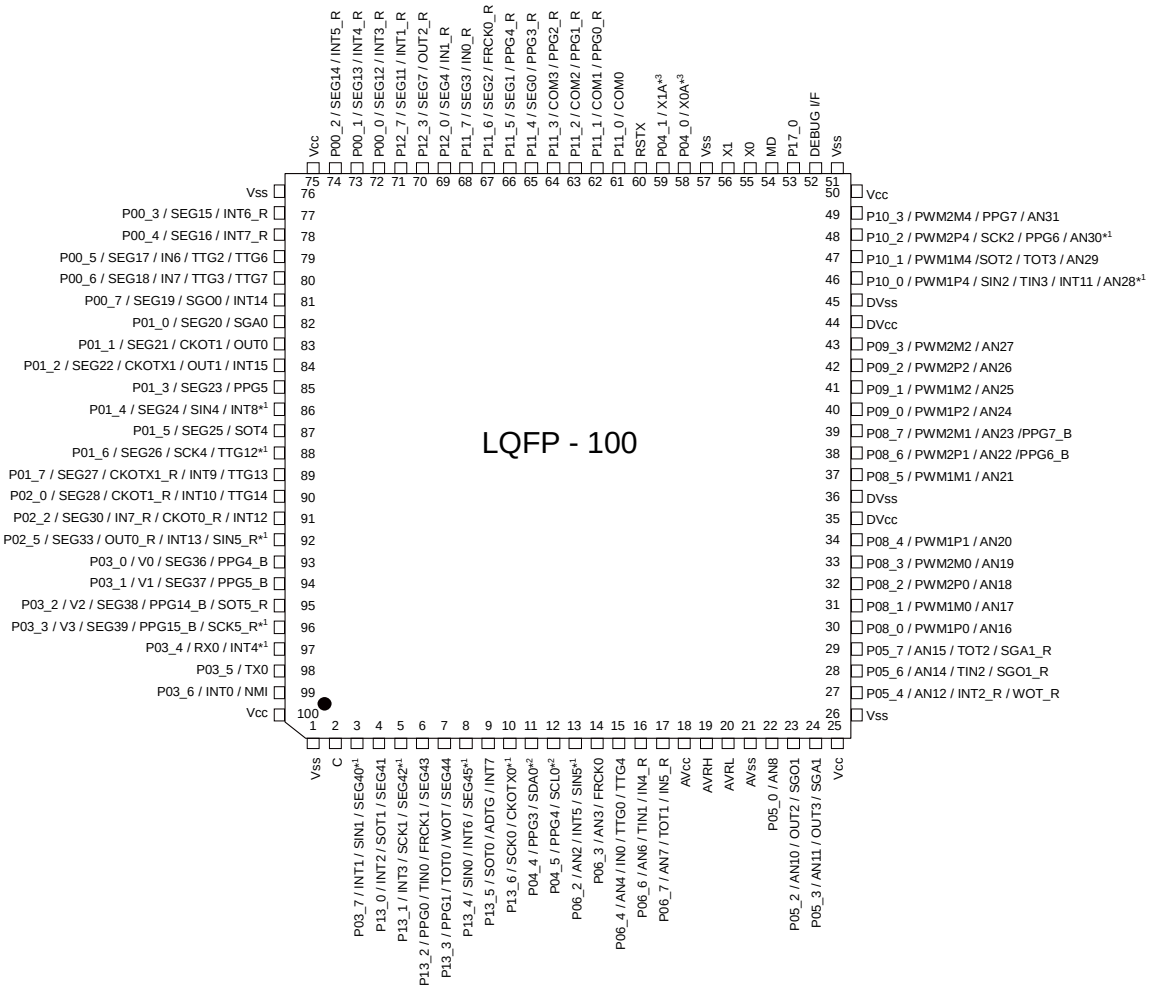
Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	F²MC-16FX
Core Size	16-Bit
Speed	32MHz
Connectivity	CANbus, I²C, LINbus, SCI, UART/USART
Peripherals	DMA, LCD, LVD, POR, PWM, WDT
Number of I/O	77
Program Memory Size	288KB (288K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 27x8/10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/mb96f696rbpmc-gse1

Contents

3. Pin Assignment

(Top view)



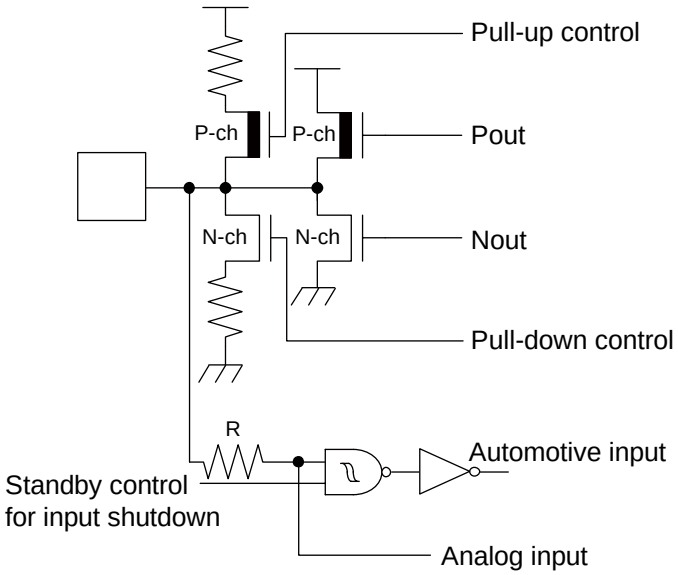
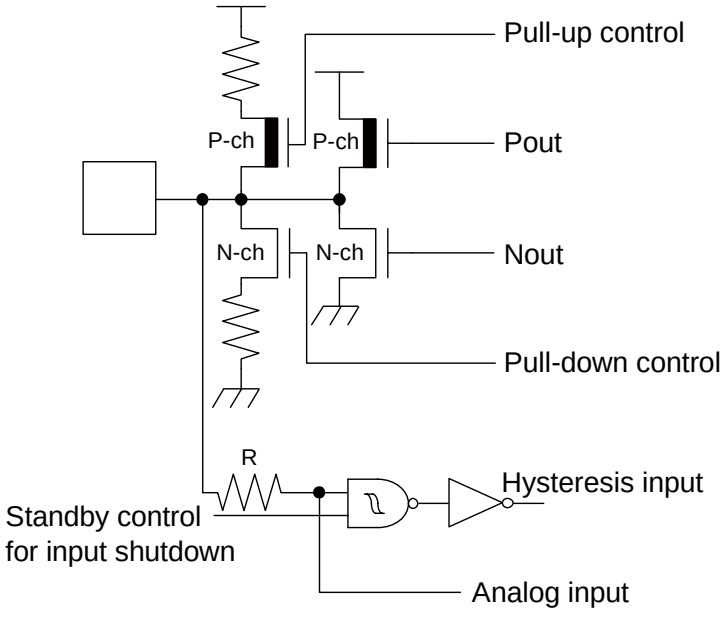
(LQI100)

*1: CMOS input level only

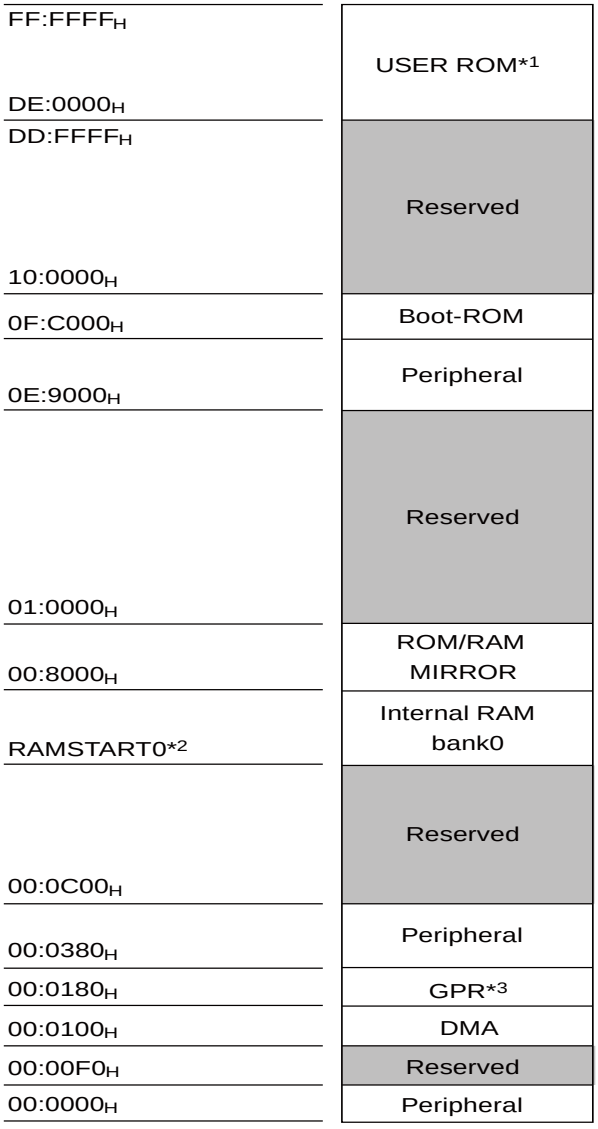
*2: CMOS input level only for I^2C

*3: Please set ROM Configuration Block (RCB) to use the subclock.

Other than those above, general-purpose pins have only Automotive input level.

Type	Circuit	Remarks
R		■ CMOS level output (programmable I_{OL} = 4mA, I_{OH} = -4mA and I_{OL} = 30mA, I_{OH} = -30mA) ■ Automotive input with input shutdown function ■ Programmable pull-up / pull-down resistor ■ Analog input
S		■ CMOS level output (programmable I_{OL} = 4mA, I_{OH} = -4mA and I_{OL} = 30mA, I_{OH} = -30mA) ■ CMOS hysteresis input with input shutdown function ■ Programmable pull-up / pull-down resistor ■ Analog input

7. Memory Map



*1: For details about USER ROM area, see "User ROM Memory Map for Flash Devices" on the following pages.

*2: For RAMSTART addresses, see the table on the next page.

*3: Unused GPR banks can be used as RAM area.

GPR: General-Purpose Register

The DMA area is only available if the device contains the corresponding resource.

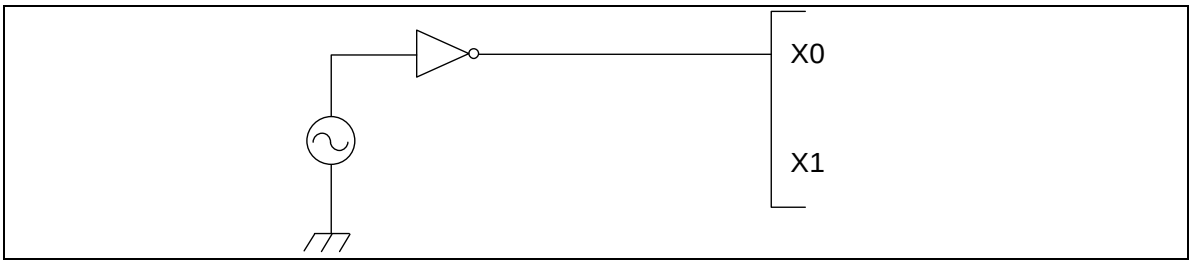
The available RAM and ROM area depends on the device.

8. RAM Start Addresses

Devices	Bank 0 RAM Size	RAMSTART0
CY96F693 CY96F695	8KB	$00:6200_H$
CY96F696	16KB	$00:4200_H$

Vector Number	Offset in Vector Table	Vector Name	Cleared by DMA	Index in ICR to Program	Description
40	$35C_H$	PPG2	Yes	40	Programmable Pulse Generator 2
41	358_H	PPG3	Yes	41	Programmable Pulse Generator 3
42	354_H	PPG4	Yes	42	Programmable Pulse Generator 4
43	350_H	PPG5	Yes	43	Programmable Pulse Generator 5
44	$34C_H$	PPG6	Yes	44	Programmable Pulse Generator 6
45	348_H	PPG7	Yes	45	Programmable Pulse Generator 7
46	344_H	-	-	46	Reserved
47	340_H	-	-	47	Reserved
48	$33C_H$	-	-	48	Reserved
49	338_H	-	-	49	Reserved
50	334_H	-	-	50	Reserved
51	330_H	-	-	51	Reserved
52	$32C_H$	PPG14	Yes	52	Programmable Pulse Generator 14
53	328_H	PPG15	Yes	53	Programmable Pulse Generator 15
54	324_H	-	-	54	Reserved
55	320_H	-	-	55	Reserved
56	$31C_H$	-	-	56	Reserved
57	318_H	-	-	57	Reserved
58	314_H	RLT0	Yes	58	Reload Timer 0
59	310_H	RLT1	Yes	59	Reload Timer 1
60	$30C_H$	RLT2	Yes	60	Reload Timer 2
61	308_H	RLT3	Yes	61	Reload Timer 3
62	304_H	-	-	62	Reserved
63	300_H	-	-	63	Reserved
64	$2FC_H$	RLT6	Yes	64	Reload Timer 6
65	$2F8_H$	ICU0	Yes	65	Input Capture Unit 0
66	$2F4_H$	ICU1	Yes	66	Input Capture Unit 1
67	$2F0_H$	-	-	67	Reserved
68	$2EC_H$	-	-	68	Reserved
69	$2E8_H$	ICU4	Yes	69	Input Capture Unit 4
70	$2E4_H$	ICU5	Yes	70	Input Capture Unit 5
71	$2E0_H$	ICU6	Yes	71	Input Capture Unit 6
72	$2DC_H$	ICU7	Yes	72	Input Capture Unit 7
73	$2D8_H$	-	-	73	Reserved
74	$2D4_H$	-	-	74	Reserved
75	$2D0_H$	-	-	75	Reserved
76	$2CC_H$	-	-	76	Reserved
77	$2C8_H$	OCU0	Yes	77	Output Compare Unit 0
78	$2C4_H$	OCU1	Yes	78	Output Compare Unit 1
79	$2C0_H$	OCU2	Yes	79	Output Compare Unit 2
80	$2BC_H$	OCU3	Yes	80	Output Compare Unit 3
81	$2B8_H$	-	-	81	Reserved

Vector Number	Offset in Vector Table	Vector Name	Cleared by DMA	Index in ICR to Program	Description
82	$2B4_H$	-	-	82	Reserved
83	$2B0_H$	-	-	83	Reserved
84	$2AC_H$	-	-	84	Reserved
85	$2A8_H$	-	-	85	Reserved
86	$2A4_H$	-	-	86	Reserved
87	$2A0_H$	-	-	87	Reserved
88	$29C_H$	-	-	88	Reserved
89	298_H	FRT0	Yes	89	Free-Running Timer 0
90	294_H	FRT1	Yes	90	Free-Running Timer 1
91	290_H	-	-	91	Reserved
92	$28C_H$	-	-	92	Reserved
93	288_H	RTC0	No	93	Real Time Clock
94	284_H	CAL0	No	94	Clock Calibration Unit
95	280_H	SG0	No	95	Sound Generator 0
96	$27C_H$	IIC0	Yes	96	I^2C interface 0
97	278_H	-	-	97	Reserved
98	274_H	ADC0	Yes	98	A/D Converter 0
99	270_H	-	-	99	Reserved
100	$26C_H$	-	-	100	Reserved
101	268_H	LINR0	Yes	101	LIN USART 0 RX
102	264_H	LINT0	Yes	102	LIN USART 0 TX
103	260_H	LINR1	Yes	103	LIN USART 1 RX
104	$25C_H$	LINT1	Yes	104	LIN USART 1 TX
105	258_H	LINR2	Yes	105	LIN USART 2 RX
106	254_H	LINT2	Yes	106	LIN USART 2 TX
107	250_H	-	-	107	Reserved
108	$24C_H$	-	-	108	Reserved
109	248_H	LINR4	Yes	109	LIN USART 4 RX
110	244_H	LINT4	Yes	110	LIN USART 4 TX
111	240_H	LINR5	Yes	111	LIN USART 5 RX
112	$23C_H$	LINT5	Yes	112	LIN USART 5 TX
113	238_H	-	-	113	Reserved
114	234_H	-	-	114	Reserved
115	230_H	-	-	115	Reserved
116	$22C_H$	-	-	116	Reserved
117	228_H	-	-	117	Reserved
118	224_H	-	-	118	Reserved
119	220_H	-	-	119	Reserved
120	$21C_H$	-	-	120	Reserved
121	218_H	SG1	No	121	Sound Generator 1
122	214_H	-	-	122	Reserved
123	210_H	-	-	123	Reserved

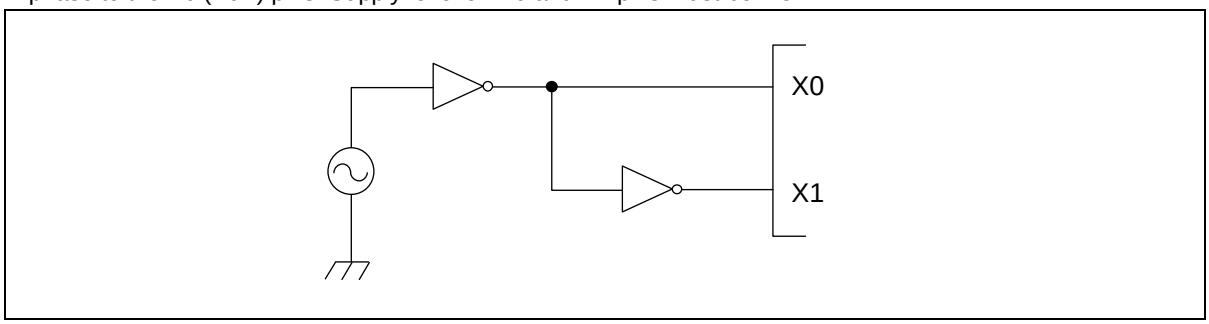


13.3.2 *Single Phase External Clock for Sub Oscillator*

When using a single phase external clock for the Sub oscillator, “External clock mode” must be selected and X0A/P04_0 pin must be driven. X1A/P04_1 pin can be configured as GPIO.

13.3.3 *Opposite Phase External Clock*

When using an opposite phase external clock, X1 (X1A) pins must be supplied with a clock signal which has the opposite phase to the X0 (X0A) pins. Supply level on X0 and X1 pins must be 1.8V.



13.4 Notes on PLL Clock Mode Operation

If the microcontroller is operated with PLL clock mode and no external oscillator is operating or no external clock is supplied, the microcontroller attempts to work with the free oscillating PLL. Performance of this operation, however, cannot be guaranteed.

13.5 Power Supply Pins (Vcc/Vss)

It is required that all V_{CC}-level as well as all V_{SS}-level power supply pins are at the same potential. If there is more than one V_{CC} or V_{SS} level, the device may operate incorrectly or be damaged even within the guaranteed operating range.

Vcc and Vss pins must be connected to the device from the power supply with lowest possible impedance.

The smoothing capacitor at Vcc pin must use the one of a capacity value that is larger than Cs.

Besides this, as a measure against power supply noise, it is required to connect a bypass capacitor of about 0.1μF between Vcc and Vss pins as close as possible to Vcc and Vss pins.

13.6 Crystal Oscillator and ceramic resonator Circuit

Noise at X0, X1 pins or X0A, X1A pins might cause abnormal operation. It is required to provide bypass capacitors with shortest possible distance to X0, X1 pins and X0A, X1A pins, crystal oscillator (or ceramic resonator) and ground lines, and, to the utmost effort, that the lines of oscillation circuit do not cross the lines of other circuits.

It is highly recommended to provide a printed circuit board art work surrounding X0, X1 pins and X0A, X1A pins with a ground area for stabilizing the operation.

It is highly recommended to evaluate the quartz/MCU or resonator/MCU system at the quartz or resonator manufacturer, especially when using low-Q resonators at higher frequencies.

13.7 Turn on Sequence of Power Supply to A/D Converter and Analog Inputs

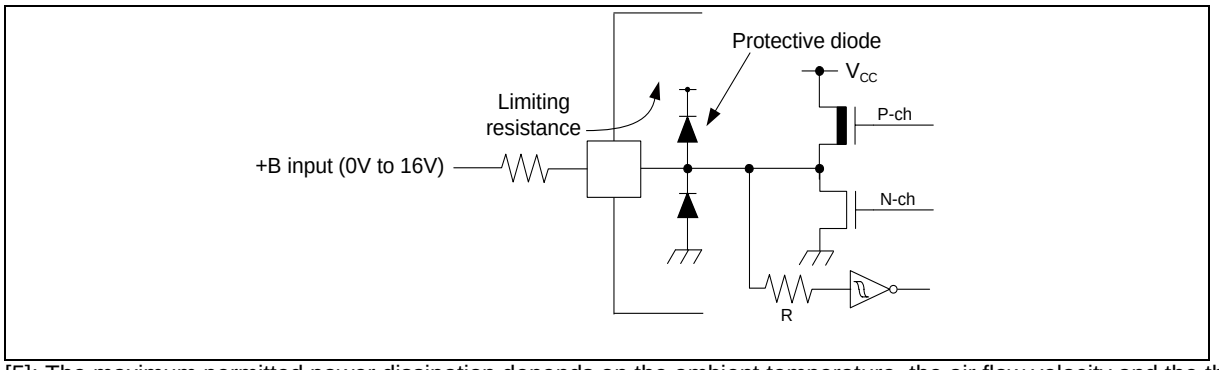
It is required to turn the A/D converter power supply (AV_{CC}, AVRH, AVRL) and analog inputs (ANn) on after turning the digital power supply (V_{CC}) on.

14. Electrical Characteristics

14.1 Absolute Maximum Ratings

Parameter	Symbol	Condition	Rating		Unit	Remarks
			Min	Max		
Power supply voltage[1]	V_{CC}	-	V_{SS} - 0.3	V_{SS} + 6.0	V	
Analog power supply voltage[1]	AV_{CC}	-	V_{SS} - 0.3	V_{SS} + 6.0	V	$V_{CC} = AV_{CC}$[2]
Analog reference voltage[1]	AVRH, AVRL	-	V_{SS} - 0.3	V_{SS} + 6.0	V	$AV_{CC} \geq$ AVRH, $AV_{CC} \geq$ AVRL, AVRH > AVRL, AVRL ≥ AV_{SS}
SMC Power supply[1]	DV_{CC}	-	V_{SS} - 0.3	V_{SS} + 6.0	V	$V_{CC} = AV_{CC} = DV_{CC}$[2]
LCD power supply voltage[1]	V0 to V3	-	V_{SS} - 0.3	V_{SS} + 6.0	V	V0 to V3 must not exceed V_{CC}
Input voltage[1]	V_I	-	V_{SS} - 0.3	V_{SS} + 6.0	V	$V_I \leq (D)V_{CC} + 0.3V$[3]
Output voltage[1]	V_O	-	V_{SS} - 0.3	V_{SS} + 6.0	V	$V_O \leq (D)V_{CC} + 0.3V$[3]
Maximum Clamp Current	I_{CLAMP}	-	-4.0	+4.0	mA	Applicable to general purpose I/O pins [4]
Total Maximum Clamp Current	$\Sigma\lvert I_{CLAMP}\rvert$	-	-	25	mA	Applicable to general purpose I/O pins [4]
"L" level maximum output current	I_{OL}	-	-	15	mA	Normal port
	I_{OLSMC}	T_A= -40°C	-	52	mA	High current port
		T_A= +25°C	-	39	mA	
		T_A= +85°C	-	32	mA	
		T_A= +105°C	-	30	mA	
"L" level average output current	I_{OLAV}	-	-	4	mA	Normal port
	$I_{OLAVSMC}$	T_A= -40°C	-	40	mA	High current port
		T_A= +25°C	-	30	mA	
		T_A= +85°C	-	25	mA	
		T_A= +105°C	-	23	mA	
"L" level maximum overall output current	ΣI_{OL}	-	-	50	mA	Normal port
	ΣI_{OLSMC}	-	-	260	mA	High current port
"L" level average overall output current	ΣI_{OLAV}	-	-	25	mA	Normal port
	$\Sigma I_{OLAVSMC}$	-	-	170	mA	High current port

Sample recommended circuits:



[5]: The maximum permitted power dissipation depends on the ambient temperature, the air flow velocity and the thermal conductance of the package on the PCB.
The actual power dissipation depends on the customer application and can be calculated as follows:
$P_D = P_{IO} + P_{INT}$
$P_{IO} = \Sigma (V_{OL} \times I_{OL} + V_{OH} \times I_{OH})$ (I/O load power dissipation, sum is performed on all I/O ports)
$P_{INT} = V_{CC} \times (I_{CC} + I_A)$ (internal power dissipation)
I_{CC} is the total core current consumption into V_{CC} as described in the “DC characteristics” and depends on the selected operation mode and clock frequency and the usage of functions like Flash programming.
I_A is the analog current consumption into AV_{CC}.

[6]: Worst case value for a package mounted on single layer PCB at specified T_A without air flow.

WARNING:

Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

14.2 Recommended Operating Conditions

(V_{SS} = AV_{SS} = DV_{SS} = 0V)

Parameter	Symbol	Value			Unit	Remarks
		Min	Typ	Max		
Power supply voltage	V_{CC}, AV_{CC}, DV_{CC}	2.7	-	5.5	V	
		2.0	-	5.5	V	Maintains RAM data in stop mode
Smoothing capacitor at C pin	C_S	0.5	1.0 to 3.9	4.7	µF	1.0µF (Allowance within ± 50%) 3.9µF (Allowance within ± 20%) Please use the ceramic capacitor or the capacitor of the frequency response of this level. The smoothing capacitor at V_{CC} must use the one of a capacity value that is larger than C_S.

WARNING:

The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges. Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure. No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their representatives beforehand.

Parameter	Symbol	Pin Name	Conditions	Value			Unit	Remarks
				Min	Typ	Max		
Power supply current in Sleep modes[1]	I_{CCSPLL}	Vcc	PLL Sleep mode with CLKS1/2 = CLKP1/2 = 32MHz (CLKRC and CLKSC stopped)	-	9.5	-	mA	T_A = +25°C
				-	-	15	mA	T_A = +105°C
	$I_{CCSMAIN}$		Main Sleep mode with CLKS1/2 = CLKP1/2 = 4MHz, SMCR:LPMSS = 0 (CLKPLL, CLKRC and CLKSC stopped)	-	1.1	-	mA	T_A = +25°C
				-	-	4.7	mA	T_A = +105°C
	I_{CCSRCH}		RC Sleep mode with CLKS1/2 = CLKP1/2 = CLKRC = 2MHz, SMCR:LPMSS = 0 (CLKMC, CLKPLL and CLKSC stopped)	-	0.6	-	mA	T_A = +25°C
				-	-	4.1	mA	T_A = +105°C
	I_{CCSRCL}		RC Sleep mode with CLKS1/2 = CLKP1/2 = CLKRC = 100kHz (CLKMC, CLKPLL and CLKSC stopped)	-	0.07	-	mA	T_A = +25°C
				-	-	2.9	mA	T_A = +105°C
	I_{CCSSUB}		Sub Sleep mode with CLKS1/2 = CLKP1/2 = 32kHz, (CLKMC, CLKPLL and CLKRC stopped)	-	0.04	-	mA	T_A = +25°C
				-	-	2.7	mA	T_A = +105°C
Power supply current in Timer modes[2]	I_{CCTPLL}	Vcc	PLL Timer mode with CLKPLL = 32MHz (CLKRC and CLKSC stopped)	-	1800	2250	µA	T_A = +25°C
				-	-	3220	µA	T_A = +105°C
	$I_{CCTMAIN}$		Main Timer mode with CLKMC = 4MHz, SMCR:LPMSS = 0 (CLKPLL, CLKRC and CLKSC stopped)	-	285	330	µA	T_A = +25°C
				-	-	1200	µA	T_A = +105°C
	I_{CCTRCH}		RC Timer mode with CLKRC = 2MHz, SMCR:LPMSS = 0 (CLKPLL, CLKMC and CLKSC stopped)	-	160	215	µA	T_A = +25°C
				-	-	1110	µA	T_A = +105°C
	I_{CCTRCL}		RC Timer mode with CLKRC = 100kHz, (CLKPLL, CLKMC and CLKSC stopped)	-	35	75	µA	T_A = +25°C
				-	-	910	µA	T_A = +105°C
	I_{CCTSUB}		Sub Timer mode with CLKSC = 32kHz (CLKMC, CLKPLL and CLKRC stopped)	-	25	65	µA	T_A = +25°C
				-	-	885	µA	T_A = +105°C

Parameters	Symbol	Pin Name	Conditions	Value			Unit	Remarks
				Min	Typ	Max		
"H" level output voltage	V_{OH4}	4mA type	$4.5V \le (D)V_{CC} \le 5.5V$ I_{OH} = -4mA	$(D)V_{CC}$- 0.5	-	$(D)V_{CC}$	V	
			$2.7V \le (D)V_{CC} < 4.5V$ I_{OH} = -1.5mA					
	V_{OH30}	High Drive type*	$4.5V \le DV_{CC} \le 5.5V$ I_{OH} = -52mA	DV_{CC}- 0.5	-	DV_{CC}	V	T_A = -40°C
			$2.7V \le DV_{CC} < 4.5V$ I_{OH} = -18mA					
			$4.5V \le DV_{CC} \le 5.5V$ I_{OH} = -39mA					T_A = +25°C
			$2.7V \le DV_{CC} < 4.5V$ I_{OH} = -16mA					
			$4.5V \le DV_{CC} \le 5.5V$ I_{OH} = -32mA					T_A = +85°C
			$2.7V \le DV_{CC} < 4.5V$ I_{OH} = -14.5mA					
			$4.5V \le DV_{CC} \le 5.5V$ I_{OH} = -30mA					T_A = +105°C
			$2.7V \le DV_{CC} < 4.5V$ I_{OH} = -14mA					
	V_{OH3}	3mA type	$4.5V \le V_{CC} \le 5.5V$ I_{OH} = -3mA	V_{CC}- 0.5	-	V_{CC}	V	
			$2.7V \le V_{CC} < 4.5V$ I_{OH} = -1.5mA					

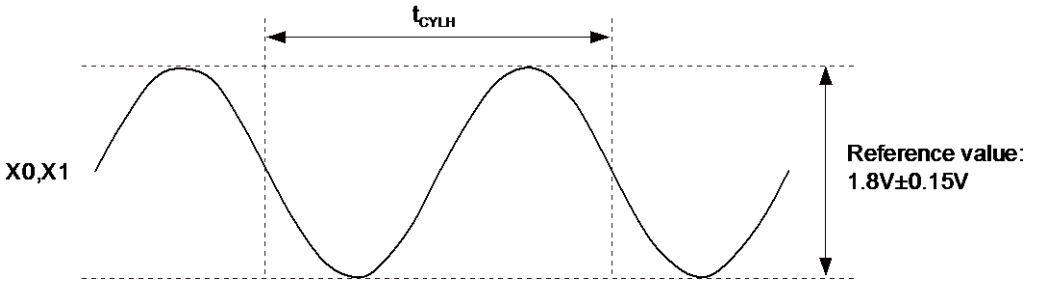
14.4 AC Characteristics

14.4.1 *Main Clock Input Characteristics*

(V_{CC} = AV_{CC} = DV_{CC} = 2.7V to 5.5V, VD=1.8V±0.15V, V_{SS} = AV_{SS} = DV_{SS} = 0V, T_A = - 40°C to + 105°C)

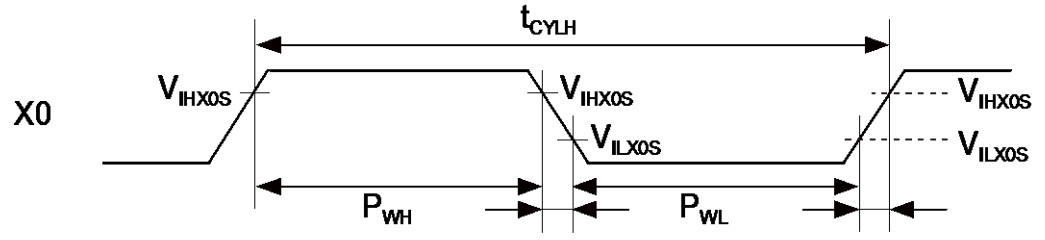
Parameter	Symbol	Pin Name	Value			Unit	Remarks
			Min	Typ	Max		
Input frequency	f_C	X0, X1	4	-	8	MHz	When using a crystal oscillator, PLL off
			-	-	8	MHz	When using an opposite phase external clock, PLL off
			4	-	8	MHz	When using a crystal oscillator or opposite phase external clock, PLL on
Input frequency	f_{FCI}	X0	-	-	8	MHz	When using a single phase external clock in “Fast Clock Input mode”, PLL off
			4	-	8	MHz	When using a single phase external clock in “Fast Clock Input mode”, PLL on
Input clock cycle	t_{CYLH}	-	125	-	-	ns	
Input clock pulse width	P_{WH}, P_{WL}	-	55	-	-	ns	

When using the crystal oscillator



The amplitude changes by resistance, capacity which added outside or the difference of the device.

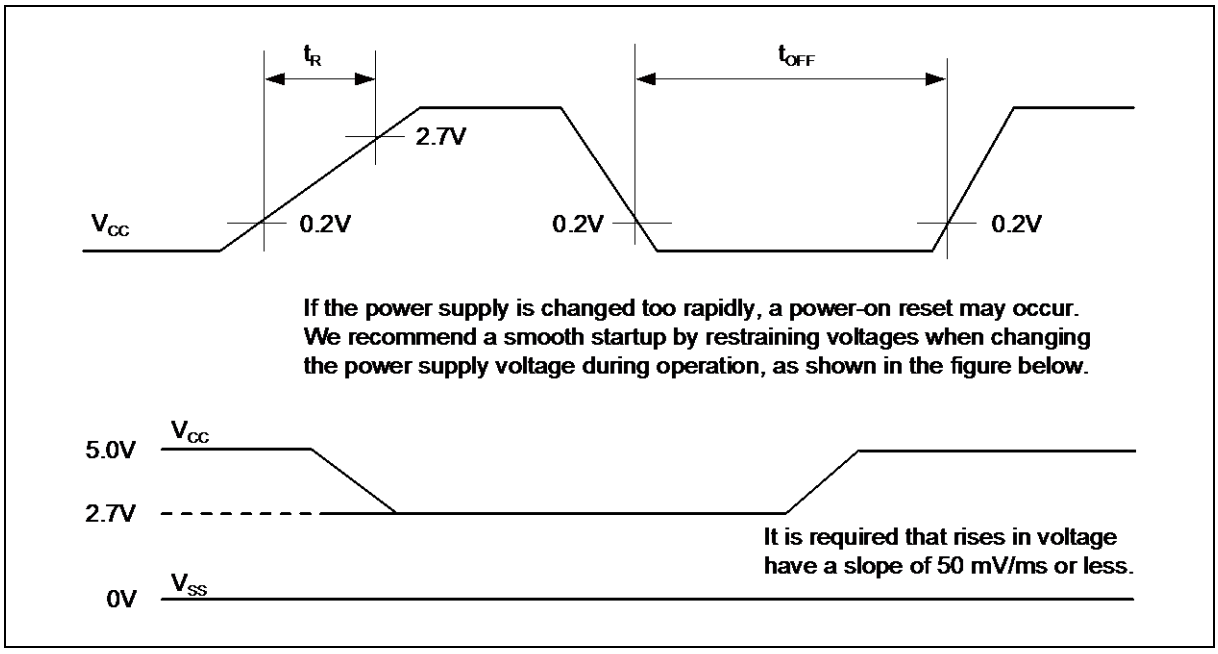
When using the external clock



14.4.7 *Power-on Reset Timing*

(V_{CC} = AV_{CC} = DV_{CC} = 2.7V to 5.5V, V_{SS} = AV_{SS} = DV_{SS} = 0V, T_A = - 40°C to + 105°C)

Parameter	Symbol	Pin Name	Value			Unit
			Min	Typ	Max	
Power on rise time	t_R	Vcc	0.05	-	30	ms
Power off time	t_{OFF}	Vcc	1	-	-	ms



14.4.10 *I²C Timing*

(V_{CC} = AV_{CC} = DV_{CC} = 2.7V to 5.5V, V_{SS} = AV_{SS} = DV_{SS} = 0V, T_A = - 40°C to + 105°C)

Parameter	Symbol	Conditions	Typical Mode		High-Speed Mode[4]		Unit
			Min	Max	Min	Max	
SCL clock frequency	f_{SCL}	C_L = 50pF, R = (Vp/I_{OL})[1]	0	100	0	400	kHz
(Repeated) START condition hold time SDA ↓ → SCL ↓	t_{HDSTA}		4.0	-	0.6	-	µs
SCL clock "L" width	t_{LOW}		4.7	-	1.3	-	µs
SCL clock "H" width	t_{HIGH}		4.0	-	0.6	-	µs
(Repeated) START condition setup time SCL ↑ → SDA ↓	t_{SUSTA}		4.7	-	0.6	-	µs
Data hold time SCL ↓ → SDA ↓ ↑	t_{HDDAT}		0	3.45[2]	0	0.9[3]	µs
Data setup time SDA ↓ ↑ →SCL ↑	t_{SUDAT}		250	-	100	-	ns
STOP condition setup time SCL ↑ → SDA ↑	t_{SUSTO}		4.0	-	0.6	-	µs
Bus free time between "STOP condition" and "START condition"	t_{BUS}		4.7	-	1.3	-	µs
Pulse width of spikes which will be suppressed by input noise filter	t_{SP}	-	0	(1-1.5) ×t_{CLKP1}[5]	0	(1-1.5) ×t_{CLKP1}[5]	ns

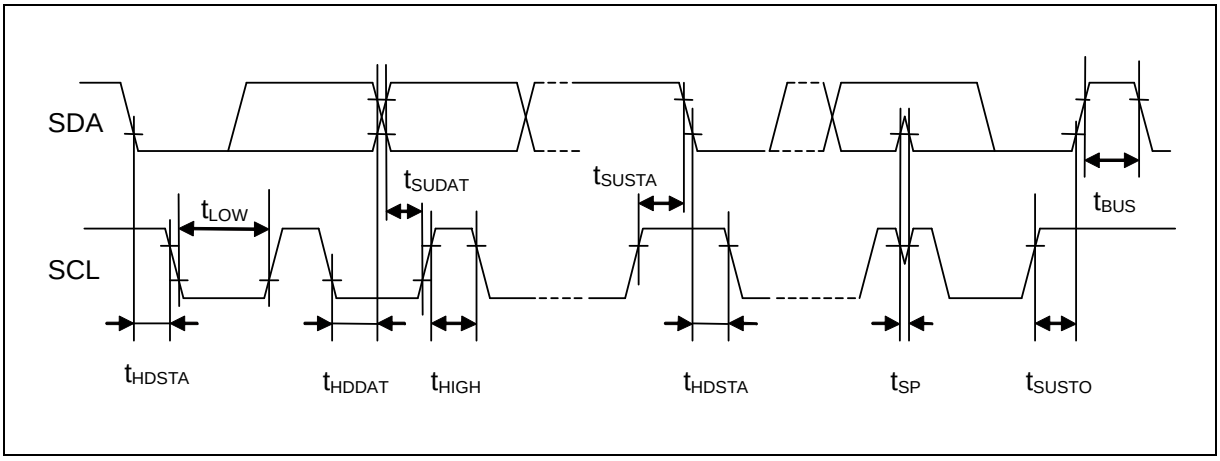
[1]: R and C_L represent the pull-up resistance and load capacitance of the SCL and SDA lines, respectively. Vp indicates the power supply voltage of the pull-up resistance and I_{OL} indicates V_{OL} guaranteed current.

[2]: The maximum t_{HDDAT} only has to be met if the device does not extend the "L" width (t_{LOW}) of the SCL signal.

[3]: A high-speed mode I^2C bus device can be used on a standard mode I^2C bus system as long as the device satisfies the requirement of "t_{SUDAT} ≥ 250ns".

[4]: For use at over 100 kHz, set the peripheral clock1 (CLKP1) to at least 6 MHz.

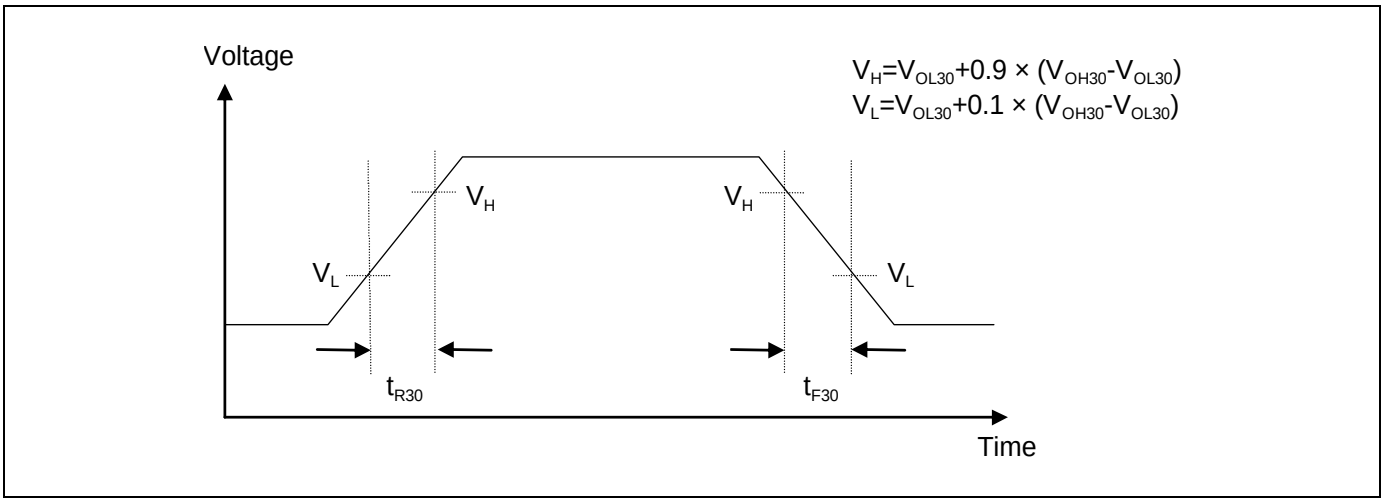
[5]: t_{CLKP1} indicates the peripheral clock1 (CLKP1) cycle time.



14.6 High Current Output Slew Rate

(V_{CC} = AV_{CC} = DV_{CC} = 2.7V to 5.5V, V_{SS} = AV_{SS} = DV_{SS} = 0V, T_A = - 40°C to + 105°C)

Parameter	Symbol	Pin Name	Conditions	Value			Unit	Remarks
				Min	Typ	Max		
Output rise/fall time	t_{R30}, t_{F30}	P08_m, P09_m, P10_m	Outputs driving strength set to "30mA"	15	-	75	ns	C_L=85pF



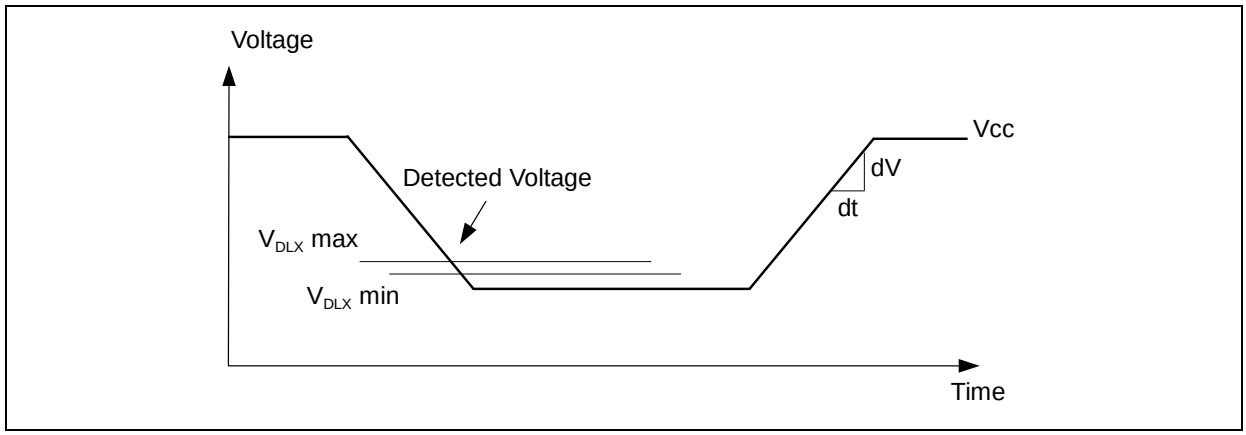
14.7 Low Voltage Detection Function Characteristics

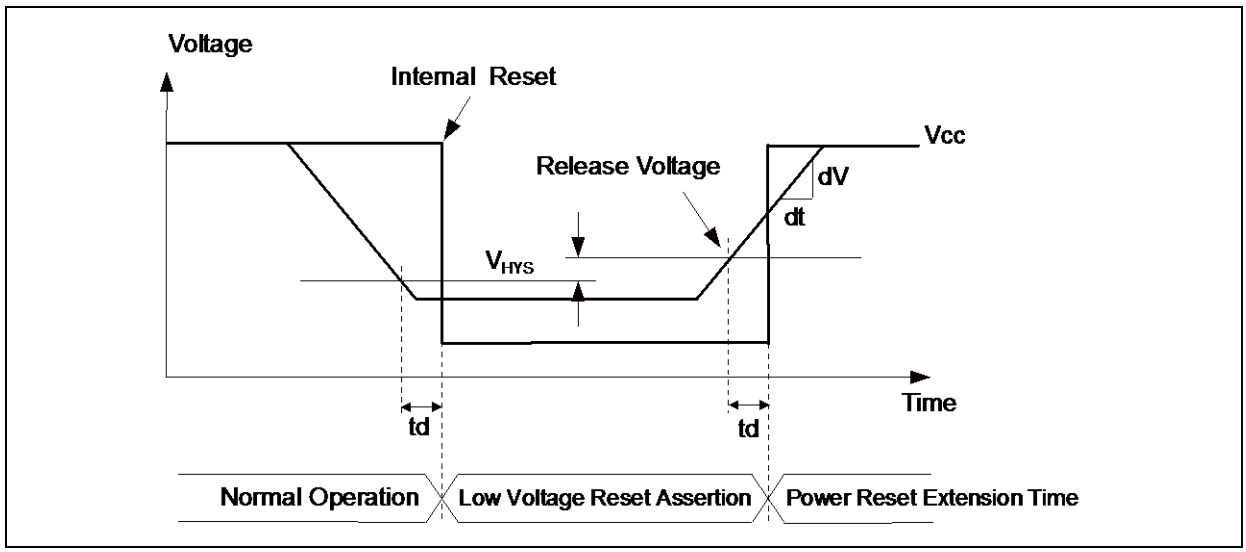
(V_{CC} = AV_{CC} = DV_{CC} = 2.7V to 5.5V, V_{SS} = AV_{SS} = DV_{SS} = 0V, T_A = - 40°C to + 105°C)

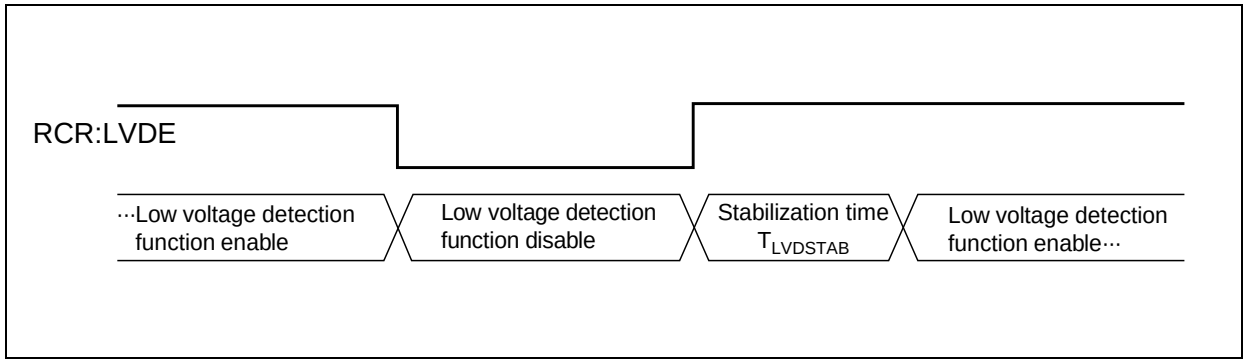
Parameter	Symbol	Conditions	Value			Unit
			Min	Typ	Max	
Detected voltage[1]	V_{DL0}	CILCR:LVL = 0000_B	2.70	2.90	3.10	V
	V_{DL1}	CILCR:LVL = 0001_B	2.79	3.00	3.21	V
	V_{DL2}	CILCR:LVL = 0010_B	2.98	3.20	3.42	V
	V_{DL3}	CILCR:LVL = 0011_B	3.26	3.50	3.74	V
	V_{DL4}	CILCR:LVL = 0100_B	3.45	3.70	3.95	V
	V_{DL5}	CILCR:LVL = 0111_B	3.73	4.00	4.27	V
	V_{DL6}	CILCR:LVL = 1001_B	3.91	4.20	4.49	V
Power supply voltage change rate[2]	dV/dt	-	- 0.004	-	+ 0.004	V/µs
Hysteresis width	V_{HYS}	CILCR:LVHYS=0	-	-	50	mV
		CILCR:LVHYS=1	80	100	120	mV
Stabilization time	$T_{LVDSTAB}$	-	-	-	75	µs
Detection delay time	t_d	-	-	-	30	µs

[1]: If the power supply voltage fluctuates within the time less than the detection delay time (t_d), there is a possibility that the low voltage detection will occur or stop after the power supply voltage passes the detection range.

[2]: In order to perform the low voltage detection at the detection voltage (V_{DLX}), be sure to suppress fluctuation of the power supply voltage within the limits of the change ration of power supply voltage.


Voltage
Vcc
dV
dt
Detected Voltage
V_{DLX} max
V_{DLX} min
Time


Voltage
Internal Reset
Vcc
Release Voltage
dV
dt
V_{HYS}
Time
td
td
Normal Operation
Low Voltage Reset Assertion
Power Reset Extension Time


RCR:LVDE
···Low voltage detection function enable
Low voltage detection function disable
Stabilization time $T_{LVDSTAB}$
Low voltage detection function enable···

14.8 Flash Memory Write/Erase Characteristics

(V_{CC} = AV_{CC} = DV_{CC} = 2.7V to 5.5V, V_{SS} = AV_{SS} = DV_{SS} = 0V, T_A = - 40°C to + 105°C)

Parameter		Conditions	Value			Unit	Remarks
			Min	Typ	Max		
Sector erase time	Large Sector	-	-	1.6	7.5	s	Includes write time prior to internal erase.
	Small Sector	-	-	0.4	2.1	s	
	Security Sector	-	-	0.31	1.65	s	
Word (16-bit) write time		-	-	25	400	µs	Not including system-level overhead time.
Chip erase time		-	-	8.31	40.05	s	Includes write time prior to internal erase.

Note:

While the Flash memory is written or erased, shutdown of the external power (V_{CC}) is prohibited. In the application system where the external power (V_{CC}) might be shut down while writing or erasing, be sure to turn the power off by using a low voltage detection function.

To put it concrete, change the external power in the range of change ration of power supply voltage (-0.004V/µs to +0.004V/µs) after the external power falls below the detection voltage (V_{DLX})[1].

Write/Erase cycles and data hold time

Write/Erase Cycles (Cycle)	Data Hold Time (Year)
1,000	20 [2]
10,000	10 [2]
100,000	5 [2]

[1]: See "14.7 Low Voltage Detection Function Characteristics".

[2]: This value comes from the technology qualification (using Arrhenius equation to translate high temperature measurements into normalized value at + 85°C).

Page	Section	Change Results
		Changed the Value of “Smoothing capacitor at C pin” Typ: 1.0µF → 1.0µF to 3.9µF Max: 1.5µF → 4.7µF
		Changed the Remarks of “Smoothing capacitor at C pin” Deleted “(Target value)” Added “3.9µF (Allowance within ± 20%)”
39	3. DC Characteristics (1) Current Rating	Deleted “(Target value)”
		Added the Symbol to “Power supply current in Run modes” I_{CCRCH}, I_{CCRCL}
		Changed the Conditions of I_{CCPLL}, I_{CCMAIN}, I_{CCSUB} in “Power supply current in Run modes” “Flash 0 wait” is added
		Changed the Value of “Power supply current in Run modes” I_{CCPLL} Typ: 28.5mA → 28mA (T_A = +25°C) I_{CCMAIN} Typ:5mA → 3.5mA (T_A = +25°C) Max: 10mA → 8mA (T_A = +105°C) I_{CCSUB} Typ:0.5mA → 0.1mA (T_A = +25°C) Max: 6mA → 3.3mA (T_A = +105°C)
40		Added the Symbol to “Power supply current in Sleep modes” I_{CCSRCH}, I_{CCSRCL}
		Changed the Conditions of $I_{CCSMAIN}$ in “Power supply current in Sleep modes” “SMCR:LPMSS=0” is added
		Changed the Value of “Power supply current in Sleep modes” I_{CCSPLL} Typ:10mA → 9.5m A (T_A = +25°C) $I_{CCSMAIN}$ Typ: 3mA → 1.1m A (T_A = +25°C) Max: 8mA → 4.7m A (T_A = +105°C) I_{CCSSUB} Typ: 0.3mA → 0.04m A (T_A = +25°C) Max: 4.5mA → 2.7m A (T_A = +105°C)
		Added the Symbol to “Power supply current in Timer modes” I_{CCTPLL}
		Changed the Conditions of $I_{CCTMAIN}$, I_{CCTRCH} in “Power supply current in Timer modes” “SMCR:LPMSS=0” is added
		Changed the Value of “Power supply current in Timer modes” $I_{CCTMAIN}$ Max: 355µA → 330µA (T_A = +25°C) Max: 1320µA→ 1200µA (T_A = +105°C) I_{CCTRCH} Max: 245µA → 215µA (T_A = +25°C) Max: 1230µA→ 1110µA (T_A = +105°C)
		I_{CCTRCL} Max: 105µA → 75µA (T_A = +25°C) Max: 1030µA → 910µA (T_A = +105°C) I_{CCTSUB} Typ: 90µA→ 65µA (T_A = +25°C) Max: 1000µA → 885µA (T_A = +105°C)
41	3. DC Characteristics (1) Current Rating	Changed the Value of “Power supply current in Stop modes” I_{CCH} Max: 90µA → 60µA (T_A = +25°C) Max: 1000µA → 880µA (T_A = +105°C)
		Added the Symbol $I_{CCFLASHPD}$
		Changed the Value and condition of “Power supply current for active Low Voltage detector” I_{CCLVD} Typ: 5µA, Max: 15µA, Remarks: nothing Typ: 5µA, Max: -, Remarks: T_A = +25°C Typ: -, Max: 12.5µA, Remarks: T_A = +105°C

Page	Section	Change Results
		Changed the condition of “Flash Write/Erase current” $I_{CCFLASH}$ Typ: 12.5mA, Max: 20mA, Remarks: nothing Typ: 12.5mA, Max: -, Remarks: T_A = +25°C Typ: -, Max: 20mA, Remarks: T_A = +105°C
		Changed the annotation *2 The power supply current is measured with a 4MHz external clock connected to the Main oscillator and a 32kHz external clock connected to the Sub oscillator. When Flash is not in Power-down / reset mode, $I_{CCFLASHPD}$ must be added to the Power supply current. The power supply current is measured with a 4MHz external clock connected to the Main oscillator and a 32kHz external clock connected to the Sub oscillator. The current for "On Chip Debugger" part is not included.
42	3. DC Characteristics (2) Pin Characteristics	Added the Symbol for DEBUG I/F pin V_{OLD}
43		Changed the Pin name of “Input capacitance” Other than Vcc, Vss, AVcc, AVss, AVRH, AVRL, P08_m, P09_m, P10_m Other than C, Vcc, Vss, DVcc, DVss, AVcc, AVss, AVRH, AVRL, P08_m, P09_m, P10_m
		Deleted the annotation “I_{OH} and I_{OL} are target value.”
		Added the annotation “In the case of driving stepping motor directly or high current outputs, set "1" to the bit in the Port High Drive Register (PHDRnn:HDx="1").”
46	4. AC Characteristics (1) Main Clock Input Characteristics	Changed MAX frequency for f_{FCI} in all conditions 16 → 8 Changed MIN frequency for t_{CYLH} 62.5 → 125 Changed MIN, MAX and Unit for P_{WH}, P_{WL} MIN: 30 → 55 MAX: 70 → - Unit: % → ns
		Added the figure (t_{CYLH}) when using the external clock
47	4. AC Characteristics (2) Sub Clock Input Characteristics	Added the figure (t_{CYLL}) when using the crystal oscillator clock
48	4. AC Characteristics (3) Built-in RC Oscillation Characteristics	Added “RC clock stabilization time”
49	4. AC Characteristics (5) Operating Conditions of PLL	Changed the Value of “PLL input clock frequency” Max: 16MHz → 8MHz
		Changed the Symbol of “PLL macro oscillation clock frequency” f_{PLLO} → f_{CLKVCO}